Vishay Semiconductors

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Hyperfast Rectifier, 30 A FRED Pt[®] G5



| PRIMARY CHARACTERISTICS | | | | | | | | |
|--|-------------|--|--|--|--|--|--|--|
| I _{F(AV)} | 30 A | | | | | | | |
| V _R | 1200 V | | | | | | | |
| V _F at I _F at 125 °C | 2.1 V | | | | | | | |
| t _{rr} | 26 ns | | | | | | | |
| T _J max. | 175 °C | | | | | | | |
| Package | TO-247AD 2L | | | | | | | |
| Circuit configuration | Single | | | | | | | |

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- FREE • 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | |
|--|-----------------------------------|---|-------------|-------|--|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | | |
| Repetitive peak reverse voltage | V _{RRM} | | 1200 | V | | | | | |
| Average rectified forward current | I _{F(AV)} | T _C = 105 °C, D = 0.50 | 30 | | | | | | |
| Non-repetitive peak surge current | I _{FSM} | T_{C} = 45 °C, t_{p} = 10 ms, sine wave | 210 | А | | | | | |
| Repetitive peak forward current | I _{FRM} | T _C = 105 °C, D = 0.50, f = 20 kHz | 60 | | | | | | |
| Operating junction and storage temperature | T _J , T _{Stg} | | -55 to +175 | °C | | | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | | | |
|--|-------------------------------------|---|------|------|------|---------|--|--|--|
| PARAMETER SYMBOL TEST CONDITIONS | | | | TYP. | MAX. | UNITS | | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 1200 | - | - | | | | |
| Forward voltage | V _F | I _F = 30 A | - | 2.6 | 3.15 | V | | | |
| | | I _F = 30 A, T _J = 125 °C | - | 2.1 | - | | | | |
| Reverse leakage current | | $V_{R} = V_{R}$ rated | - | - | 50 | | | | |
| Reverse leakage current | IR | $T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ | - | - | 500 | μA 0 | | | |
| Junction capacitance | CT | V _R = 200 V | - | 17 | - | pF | | | |
| Series inductance | L _S | Measured to lead 5 mm from package body | - | 8 | - | nH | | | |



RoHS COMPLIANT

HALOGEN

VS-E5PX3012L-N3



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| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified) | | | | | | | | | | |
|---|------------------|---|---|------|------|------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | | | |
| | | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100$ |) A/µs, V _R = 30 V | - | 26 | - | | | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 100 | - | ns | | | |
| | | T _J = 125 °C | | - | 150 | - | | | | |
| Peak recovery current | 1 | T _J = 25 °C | I _F = 20 A dI _F /dt = 600 A/µs V _B = 400 V | - | 12 | - | A | | | |
| | I _{RRM} | T _J = 125 °C | | - | 22 | - | | | | |
| | Q _{rr} | T _J = 25 °C | | - | 530 | - | nC | | | |
| Reverse recovery charge | | T _J = 125 °C | | - | 1550 | - | | | | |
| Bayaraa raaayany tima | t _{rr} | T _J = 25 °C | | - | 80 | - | ns | | | |
| Reverse recovery time | | T _J = 125 °C | | - | 120 | - | | | | |
| Deels receiver a current | I _{RRM} | T _J = 25 °C | $I_{\rm F} = 30 {\rm A}$ | - | 22 | - | A | | | |
| Peak recovery current | | T _J = 125 °C | dl _F /dt = 1000 A/µs V _B = 800 V | - | 37 | - | | | | |
| | | T _J = 25 °C | | - | 900 | - | nC | | | |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | 1 | - | 2300 | - | | | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | | | |
|--|-----------------------------------|-------------------------|--------------|------|------------|------------------------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | | |
| Thermal resistance, junction-to-case | R _{thJC} | | - | - | 0.8 | °C/W | | | | |
| Weight | | | - | 5.5 | - | g | | | | |
| | | | - | 0.2 | - | oz. | | | | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 175 | °C | | | | |
| Marking device | | Case style: TO-247AD 2L | E5PX3012L | | | | | | | |

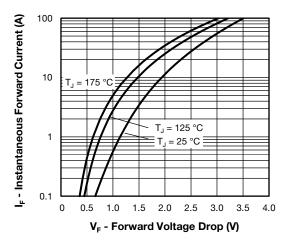


Fig. 1 - Typical Forward Voltage Drop Characteristics

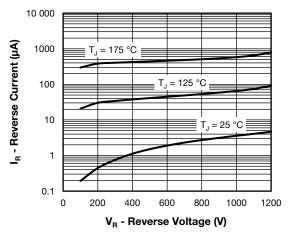
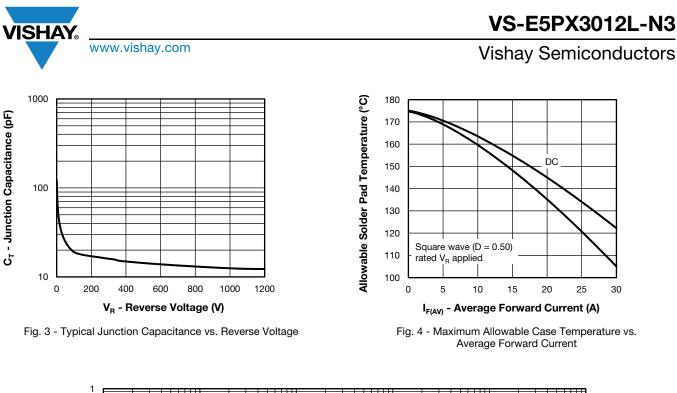


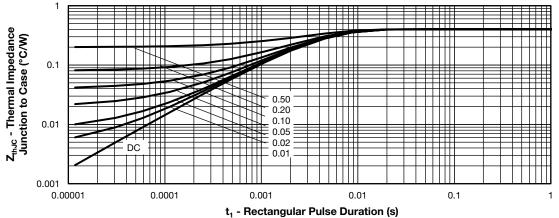
Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

2

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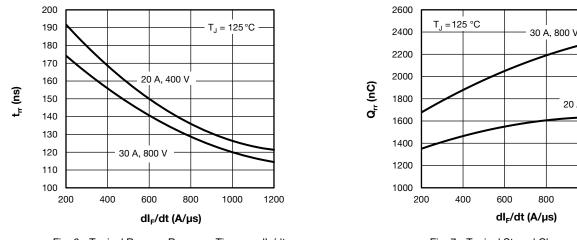


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 7 - Typical Stored Charge vs. dI_F/dt

Revision: 23-Jan-2020

3

Document Number: 96442

1200

20 A, 400 V

1000

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VS-E5PX3012L-N3

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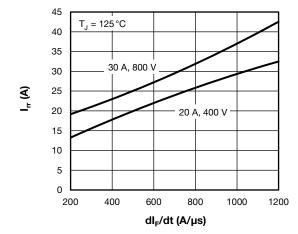


Fig. 8 - Typical Recovery Current vs. dl_F/dt

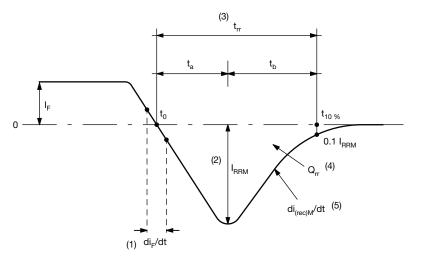


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

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- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~\text{Q}_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

| ORDERING INFORMATION (Example) | | | | | | | | | |
|--------------------------------|-------------------|------------------------|-------------------------|--|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | | |
| VS-E5PX3012L-N3 | 25 | 500 | Antistatic plastic tube | | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?95536 | | | | | |
| Part marking information | www.vishay.com/doc?95648 | | | | | |
| Spice model | www.vishay.com/doc?96684 | | | | | |

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TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

| View | <u>/ B</u> |
|------|------------|

| SYMBOL | MILLIMETERS | | INCHES | | NOTES | SYMBOL | MILLIMETERS | | INCHES | | NOTES | |
|--------|---------------------|-------|--------|-------|-------|--------|-------------|-------|--------|-------|-------|---|
| | MIN. MAX. MIN. MAX. | | STMDUL | MIN. | MAX. | MIN. | MAX. | NOTES | | | | |
| А | 4.65 | 5.31 | 0.183 | 0.209 | | | E | 15.29 | 15.87 | 0.602 | 0.625 | 3 |
| A1 | 2.21 | 2.59 | 0.087 | 0.102 | | | E1 | 13.46 | - | 0.53 | - | |
| A2 | 1.50 | 2.49 | 0.059 | 0.098 | | | е | 5.46 | BSC | 0.215 | 5 BSC | |
| b | 0.99 | 1.40 | 0.039 | 0.055 | | | ØК | 0.2 | 254 | 0.0 | 010 | |
| b1 | 0.99 | 1.35 | 0.039 | 0.053 | | | L | 19.81 | 20.32 | 0.780 | 0.800 | |
| b2 | 1.65 | 2.39 | 0.065 | 0.094 | | | L1 | 3.71 | 4.29 | 0.146 | 0.169 | |
| b3 | 1.65 | 2.34 | 0.065 | 0.092 | | | ØР | 3.56 | 3.66 | 0.14 | 0.144 | |
| С | 0.38 | 0.89 | 0.015 | 0.035 | | | Ø P1 | - | 6.98 | - | 0.275 | |
| c1 | 0.38 | 0.84 | 0.015 | 0.033 | | | Q | 5.31 | 5.69 | 0.209 | 0.224 | |
| D | 19.71 | 20.70 | 0.776 | 0.815 | 3 | | R | 4.52 | 5.49 | 0.178 | 0.216 | |
| D1 | 13.08 | - | 0.515 | - | 4 | | S | 5.51 | BSC | 0.217 | ' BSC | |
| D2 | 0.51 | 1.35 | 0.020 | 0.053 | | | | • | | • | | • |

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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